INTEGRATED CIRCUITSPOBIT样工厂, 24小时加

74LV4051 8-channel analog multiplexer/demultiplexer

DATA SHEET

Product specification Supersedes data of 1997 Jul 15 IC24 Data Handbook 1998 Jun 23







74LV4051

FEATURES

- Optimized for low voltage applications: 1.0 to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low typ "ON" resistance:
- $\begin{array}{l} 60 \ \Omega \ at \ V_{cc} V_{EE} = 4.5 \ V \\ 90 \ \Omega \ at \ V_{cc} V_{EE} = 3.0 \ V \\ 145 \ \Omega \ at \ V_{cc} V_{EE} = 2.0 \ V \end{array}$
- Logic level translation: to enable 3 V logic to communicate with ± 3 V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- I_{CC} category: MSI

DESCRIPTION

The 74LV4051 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4051.

The 74LV4051 is an 8-channel analog multiplexer/demultiplexer with three digital select inputs (S_0 to S_2) an active LOW enable input (E), eight independent inputs/outputs (Y_0 to Y_7) and a common input/output (Z).

With E LOW, one of the eight switches is selected (low impedance ON-state) by S_0 to S_2 . With \overline{E} HIGH, all switches are in the high impedance OFF-state, independent of S₀ to S₂.

 V_{CC} and GND are the supply voltage pins for the digital control inputs (S₀ to S₂, and E). The V_{CC} to GND ranges are 1.0 to 6.0 V. The analog inputs/outputs (Y₀ to Y₇ and Z) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. V_{CC} - V_{EE} may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PZH} /t _{PZL}	Turn "ON" time E to V _{OS} S _n to V _{OS}	$\begin{array}{l} C_L = 15 \text{ pF} \\ R_L = 1 K \Omega \\ V_{CC} = 3.3 \text{ V} \end{array}$	23 22	ns
t _{PHZ} /t _{PLZ}	Turn "OFF" time E to V _{OS} S _n to V _{OS}		25 20	115
Cl	Input capacitance		3.5	
C _{PD}	Power dissipation capacitance per switch	See Notes 1 and 2	25	pF
C _S	Maximum switch capacitance independent (Y) common (Z)		5 25	F.

NOTES:

1.

 $\begin{array}{l} C_{PD} \text{ is used to determine the dynamic power dissipation } (P_D \text{ in } \mu W) \\ P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \left((C_{L} + C_S) \times V_{CC}{}^2 \times f_o \right) \text{ where:} \\ f_i = \text{ input frequency in MHz; } C_L = \text{ output load capacity in } pF; \\ f_o = \text{ output frequency in MHz; } C_S = \text{maximum switch capacitance in } pF; \\ \end{array}$

 V_{CC} = supply voltage in V; $\sum ((C_L + C_S) \times V_{CC}^2 \times f_0)$ = sum of the outputs. The condition is V₁ = GND to V_{CC}.

2.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	Code
16-Pin Plastic DIL	-40°C to +125°C	74LV4051 N	74LV4051 N	SOT38-4
16-Pin Plastic SO	-40°C to +125°C	74LV4051 D	74LV4051 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV4051 DB	74LV4051 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV4051 PW	74LV4051PW DH	SOT403-1

PIN CONFIGURATION

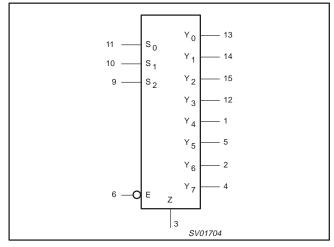
Y ₄ 1		16 V _{CC}
Y ₆ 2		15 Y ₂
Z 3		14 Y ₁
Y ₇ 4		13 Y ₀
Y ₅ 5		12 Y ₃
Ē 6		11 S ₀
V _{EE} 7		10 S ₁
GND 8		9 S ₂
	SV	l /01702

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
3	Z	Common input/output
6	Ē	Enable input (active LOW)
7	V _{EE}	Negative supply voltage
8	GND	Ground (0 V)
11, 10, 9	S ₀ to S ₂	Select inputs
13, 14, 15, 12, 1, 5, 2, 4	Y_0 to Y_7	Independent inputs/outputs
16	V _{CC}	Positive supply voltage

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LOGIC SYMBOL



FUNCTION TABLE

	INPUTS	INPUTS INPUTS				
Ē	S ₂	S ₁	S ₀	ON		
L	L	L	L	$Y_0 - Z$		
L	L	L	Н	Y ₁ – Z		
L	L	н	L	Y ₂ – Z Y ₃ – Z		
L	L	Н	Н	$Y_3 - Z$		
L	Н	L	L	$Y_4 - Z$		
L	н	L	Н	$Y_5 - Z$		
L	Н	Н	L	$Y_6 - Z$		
L	н	н	Н	$Y_4 - Z$ $Y_5 - Z$ $Y_6 - Z$ $Y_7 - Z$		
н	Х	Х	Х	None		

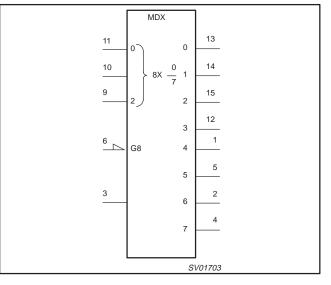
NOTES:

Н

HIGH voltage level
LOW voltage level
don't care

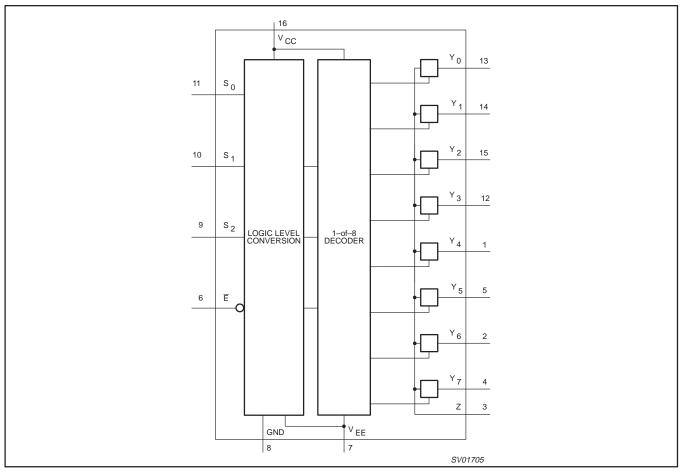
L X

LOGIC SYMBOL (IEEE/IEC)

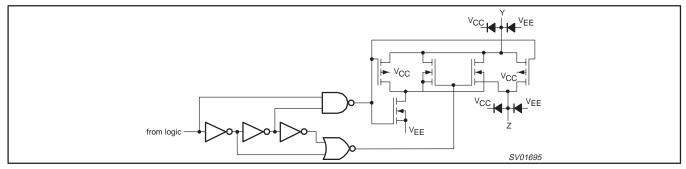


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FUNCTIONAL DIAGRAM



SCHEMATIC DIAGRAM (ONE SWITCH)



74LV4051

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_{\rm I} < -0.5 \text{ or } V_{\rm I} > V_{\rm CC} + 0.5 \text{ V}$	20	mA
$\pm I_{SK}$	DC switch diode current	$V_{\rm S}$ < -0.5 or $V_{\rm S}$ > $V_{\rm CC}$ + 0.5 V	20	mA
$\pm I_{S}$	DC switch current	$-0.5 \text{ V} < \text{V}_{\text{S}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1 and Figure 5	1.0	3.3	6.0	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0 V \text{ to } 2.0 V$ $V_{CC} = 2.0 V \text{ to } 2.7 V$ $V_{CC} = 2.7 V \text{ to } 6.0 V$			500 200 100	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 6.0V.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

						LIMITS			
SYMBOL	PARAMETER TEST CONDITIONS		NDITIONS	-40°C to +85°C			-40°C to	o +125°C	TINU T
				MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2 V		0.9			0.9		
		$V_{CC} = 2.0 V$ $V_{CC} = 2.7 \text{ to } 3.6 V$		1.4			1.4		1
VIH	HIGH level Input voltage			2.0			2.0	1	V
	Vollago	V _{CC} = 4.5 V		3.15			3.15	1	1
	V _{CC} = 6.0 V			4.20			4.20		1
		V _{CC} = 1.2 V				0.3		0.3	
		V _{CC} = 2.0 V				0.6		0.6	
VIL	LOW level Input voltage	V_{CC} = 2.7 to 3.6 V				0.8		0.8	V
	l	V _{CC} = 4.5 V				1.35		1.35	
		$V_{CC} = 6.0 V$	_{CC} = 6.0 V			1.80		1.80	
±łı	Input leakage	V _{CC} = 3.6	$V_{I} = V_{CC}$ or GND			1.0		1.0	μA
I	current	$V_{CC} = 6.0$				2.0		2.0	
-11	Analog switch	V _{CC} = 3.6	$V_{I} = V_{IH} \text{ or } V_{IL}$			1.0		1.0	
±IS	OFF-state current per channel	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 2)			2.0		2.0	μΑ
	Analog switch	V _{CC} = 3.6	$V_{I} = V_{IH} \text{ or } V_{IL}$			1.0		1.0	μΑ
±ls	ON-state current	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 3)			2.0		2.0	μ
1	Quiescent supply	V _{CC} = 3.6 V	$V_{I} = V_{CC} \text{ or } GND$			20.0		40	
ICC	current	V _{CC} = 6.0 V	$V_{IS} = GND \text{ or } V_{CC};$ $V_{OS} = V_{CC} \text{ or } GND$			40.0		80	- μΑ
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$	$V_{I} = V_{CC} - 0.6 V$			500		850	μA
		V _{CC} = 1.2 V							
	ON-resistance	V _{CC} = 2.0 V			145	325		375	1
R _{ON}	(peak)	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		90	200		235	Ω
		V_{CC} = 3.0 to 3.6 V	I _S = 1000 _μ A;		80	180		210	1
		V _{CC} = 4.5 V	$V_{IS} = V_{CC}$ to GND		60	135		160	1
		V _{CC} = 6.0 V	1 1		55	125		145	1
		V _{CC} = 1.2 V			225				
	ON-resistance	V _{CC} = 2.0 V			110	235		270	Ω
R _{ON}	(rail)	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 1000 _{\mu}\text{A};$		70	145		165	
		V _{CC} = 3.0 to 3.6 V			60	130		150	
		V _{CC} = 4.5 V	V _{IS =} GND ^{^m}		45	100		115	
		V _{CC} = 6.0 V	1		40	85		100	1

NOTES:

All typical values are measured at T_{amb} = 25°C.
 At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

3. R_{ON} (MAX) data is preliminary.

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DC ELECTRICAL CHARACTERISTICS (Continued)

						LIMITS			
SYMBOL	PARAMETER TEST COND		NDITIONS	-4(0°C to +85	5°C	-40°C to +125°C		
				MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 100 \ _{\mu}A;$ $V_{IS} = V_{CC}$		250				Ω
	ON-resistance	V _{CC} = 2.0 V			120	320		370	
R _{ON}	(rail)	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		75	195		225	1
		V _{CC} = 3.0 to 3.6 V	I _S = 1000 _μ A; V _{IS =} V _{CC}		70	175		205	Ω
		V _{CC} = 4.5 V	$V_{IS} = V_{CC}$		50	130		150	1
		V _{CC} = 6.0 V	1		45	120		135	1
		V _{CC} = 1.2 V							
	Maximum variation	V _{CC} = 2.0 V	1		5				1
ΔR _{ON}	of ON-resistance	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		4				Ω
A NON	between any two	V _{CC} = 3.0 to 3.6 V	$V_{IS} = V_{CC}$ to GND		4				32
	channels	V _{CC} = 4.5 V	1		3				1
		V _{CC} = 6.0 V	1		2				1

NOTES:
1. All typical values are measured at T_{amb} = 25°C.
2. At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

3. R_{ON} (MAX) data is preliminary.

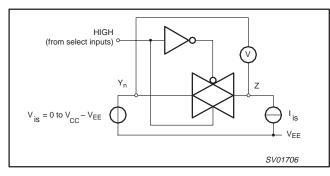


Figure 1. Test circuit for measuring ON-resistance (R_{ON}).

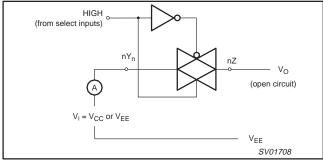


Figure 3. Test circuit for measuring ON-state current.

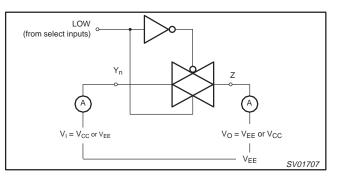


Figure 2. Test circuit for measuring OFF-state current.

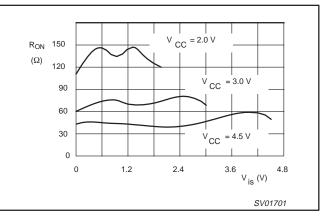


Figure 4. Typical ON-resistance (R_{on}) as a function of input voltage (V_{is}) for V_{is} = 0 to V_{CC} – V_{EE}.

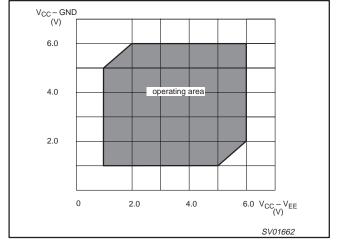


Figure 5. Guaranteed operating area as a function of the supply voltages.

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AC CHARACTERISTICS

GND = 0 V; $t_r = t_f \le 2.5ns$; C_L = 50pF

		CONDIT	ON			LIMITS			
SYMBOL	PARAMETER	CONDITI	ON	-	40 to +85 °	С	-40 to	+125 °C	UNIT
		V _{CC} (V)	OTHER	MIN	TYP ¹	МАХ	MIN	МАХ	
		1.2			25				
		2.0			9	17		20	
t _{PHL} /t _{PLH}	Propagation delay	2.7	$R_{L} = \infty;$ $C_{L} = 50 \text{ pF}$		6	13		15	ns
'PHL/'PLH	V _{is} to V _{os}	3.0 to 3.6	Figure 12		5 ²	10		12	115
		4.5	Ŭ		4	9		10	
		6.0			3	8		8	
		1.2			145				
		2.0	$R_L = 1k\Omega$;		49	94		112	
t/t	/tpzi	2.7	$C_{L} = 50 \text{pF}$		36	69		83	ns
t _{PZH} /t _{PZL}	E to V _{OS}	3.0 to 3.6	Figures 13		28 ²	55		66	
		4.5	and 1		25	47		56	
		6.0			19	38		43	
		1.2			140				
		2.0	$R_L = 1k\Omega;$		48	90		107	ns
t _{PZH} /t _{PZL}	Turn-on time	2.7	$C_{L} = 50 \text{pF}$		35	66		79	
'PZH/'PZL	S _n to V _{OS}	3.0 to 3.6	Figures 13		27 ²	53		63	
		4.5	and 1		24	45		54	
		6.0			18	34		41	
		1.2			145				
		2.0	$R_{L} = 1k\Omega$		51	93		110	
+ /+	Turn-off time	2.7	$C_L = 50 \text{pF}$		38	69		82	20
t _{PHZ} /t _{PLZ}	E to V _{OS}	3.0 to 3.6	Figures 13		30 ²	56		66	ns
		4.5	and 1		29	48		56	
		6.0			21	37		44	
		1.2			115				
		2.0	$R_{L} = 1k\Omega$		41	73		90	ns
t _{PHZ} /t _{PLZ}	Turn-off time	2.7	$C_L = 50 pF$		31	54		67	
'PHZ/'PLZ	S _n to V _{OS}	3.0 to 3.6	Figures 13		24 ²	44		54	
		4.5	and 1		22	37		46	
		6.0			17	29		36	

NOTES:

1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^{\circ}C$ 2. Typical values are measured at $V_{CC} = 3.3 \text{ V}$.

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ADDITIONAL AC CHARACTERISTICS

Recommended conditions and typical values

 $GND = 0 V; t_r = t_f \le 2.5 ns$

SYMBOL	PARAMETER	TYP.	UNIT	V _{CC} (V)	V _{is(p-p)} (V)	CONDITIONS
	Sine-wave distortion f = 1 kHz	0.80 0.40	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pf}$ Figure 9 and 10
	Sine-wave distortion f = 10 kHz	2.40 1.20	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pf}$ Figure 9 and 10
	Switch "OFF" signal feed through	-50 -50	dB	3.0 6.0	Note 1	$R_L = 600 \ \Omega$; $C_L = 50 \text{ pf}$; f= 1 MHz Figures 5 and 11
	Crosstalk between any two switches/multiplexers	-60 -60	dB	3.0 6.0	Note 1	$R_L = 600 \Omega$; $C_L = 50 pf$; f= 1 MHz Figure 8
V _(p-p)	Crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 120	mV	3.0 6.0		$R_L = 600 \ \Omega$; $C_L = 50 \ pf$; f= 1 MHz (S _n or \overline{E} , square wave between V _{CC} and GND t _r = t _f = 6 ns) Figure 8
f _{max}	Minimum frequency response (–3 dB)	180 200	MHz	3.0 6.0	Note 2	$R_L = 50 \ \Omega$; $C_L = 50 \ pF$ Figures 5, 8 and 9
CS	Maximum switch capacitance	5	pf			

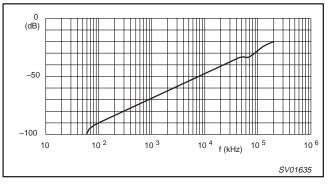
GENERAL NOTES:

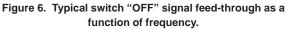
Vis is the input voltage at nY or Z terminal, whichever is assigned as an input.

V_{OS} is the output voltage at nY or Z terminal, whichever is assigned as an output.

- NOTES:
- 1.

Adjust input voltage V_{is} is 0 dBm level (0 dBm = 1 mW into 600 Ω). Adjust input voltage V_{is} is 0 dBm level at V_{OS} for 1 MHz (0 dBm = 1 mW into 50 Ω). 2.





NOTES TO FIGURES 6 AND 7:

Test conditions: V_{CC} = 3.0 V; GND = 0 V; V_{EE} = -3.0 V; R_L = 50 Ω ; R_{SOURCE} = 1k Ω .

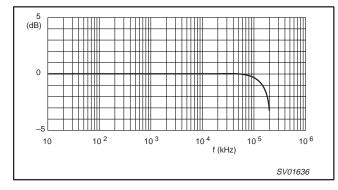


Figure 7. Typical frequency response.

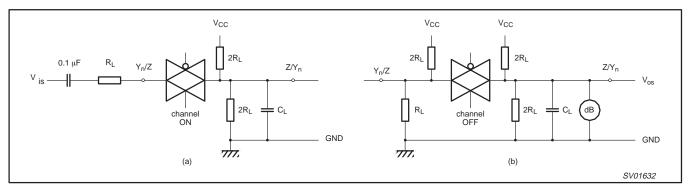


Figure 8. Test circuit for measuring crosstalk between any two switches. (a) channel ON condition; (b) channel OFF condition.

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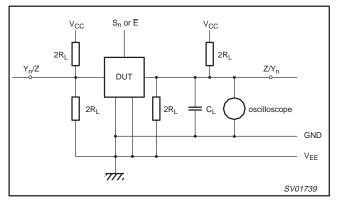


Figure 9. Test circuit for measuring crosstalk between control and any switch.

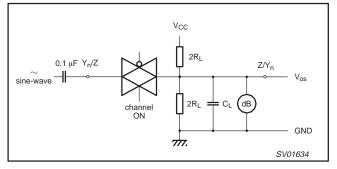


Figure 10. Test circuit for measuring minimum frequency response.

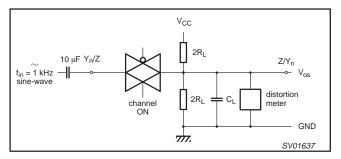
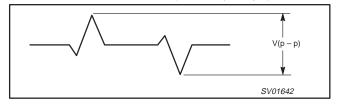


Figure 11. Test circuit for measuring sine-wave distortion.

NOTE TO FIGURE 8: The crosstalk is defined as follows (oscilloscope output):



NOTE TO FIGURE 9:

Adjust input voltage to obtain 0 dBm at V_{OS} when F_{in} = 1 MHz. After set-up frequency of f_{in} is increased to obtain a reading of –3 dB at V_{OS}.

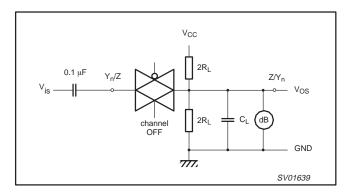


Figure 12. Test circuit for measuring switch "OFF" signal feed-through.

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WAVEFORMS

 $\begin{array}{l} V_{M} = 1.5 \ V \ at \ 2.7 \ V \leq V_{CC} \leq 3.6 \ V \\ V_{M} = 0.5 \times V_{CC} \ at \ 2.7 \ V > V_{CC} > 3.6 \ V \\ V_{OL} \ and \ V_{OH} \ are \ the typical \ output \ voltage \ drop \ that \ occur \ with \ the \ output \ load \\ V_{x} = V_{OL} + 0.3 \ V \ at \ 2.7 \ V \leq V_{CC} \leq 3.6 \ V \\ V_{x} = V_{OL} + 0.1 \times V_{CC} \ at \ 2.7 \ V > V_{CC} > 3.6 \ V \\ V_{Y} = V_{OH} - 0.3 \ V \ at \ 2.7 \ V \leq V_{CC} \leq 3.6 \ V \\ V_{Y} = V_{OH} - 0.1 \times V_{CC} \ at \ 2.7 \ V > V_{CC} > 3.6 \ V \\ V_{Y} = V_{OH} - 0.1 \times V_{CC} \ at \ 2.7 \ V > V_{CC} > 3.6 \ V \end{array}$

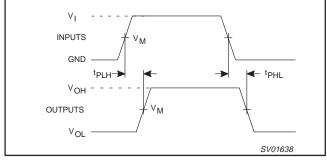


Figure 13. Input (Vis) to output (Vos) propagation delays.

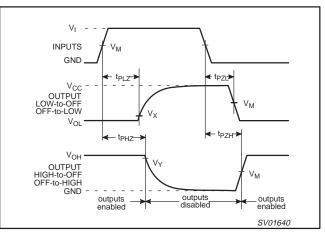


Figure 14. Turn-on and turn-off times for the inputs (S_n, \overline{E}) to the output (V_{os}) .

TEST CIRCUIT

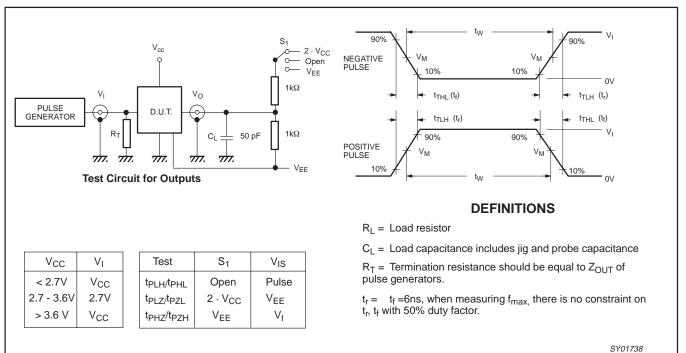
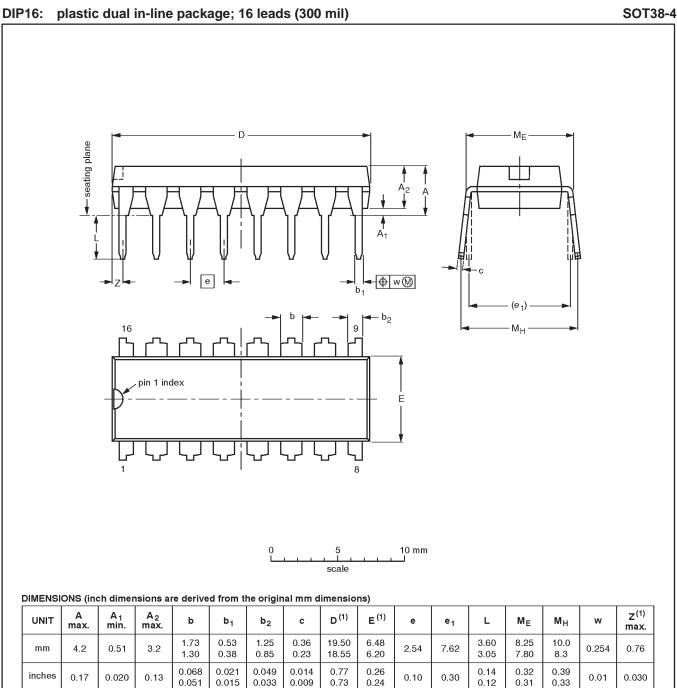


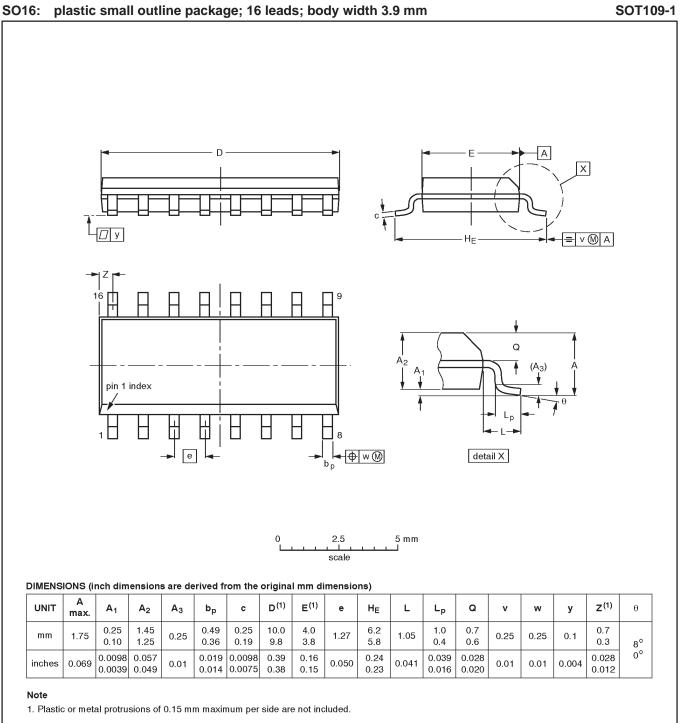
Figure 15. Load circuitry for switching times.



Note

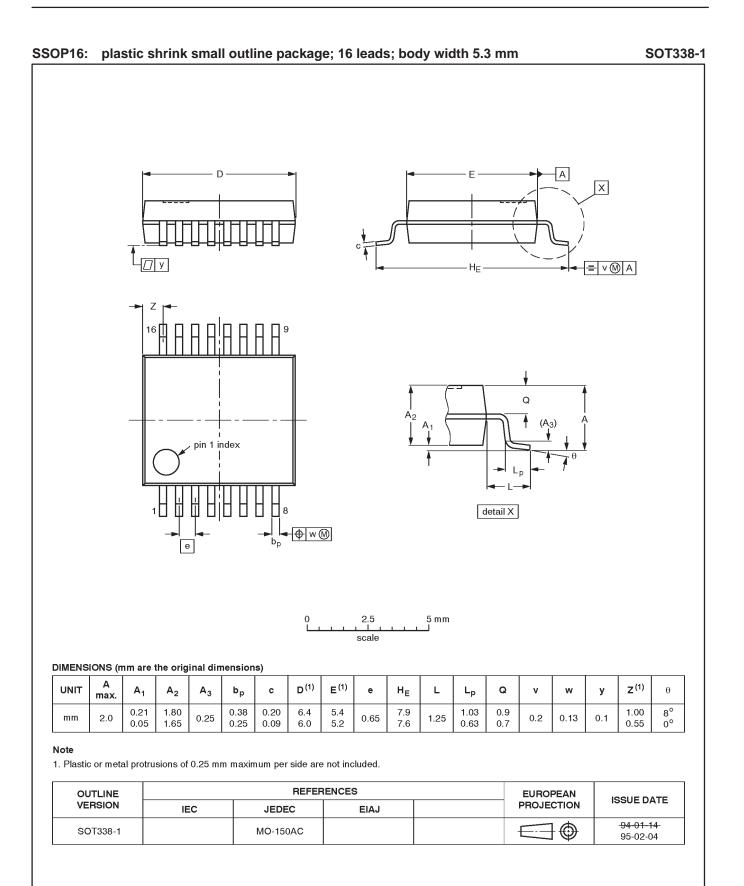
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE			EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT38-4					-92-11-17 95-01-14	

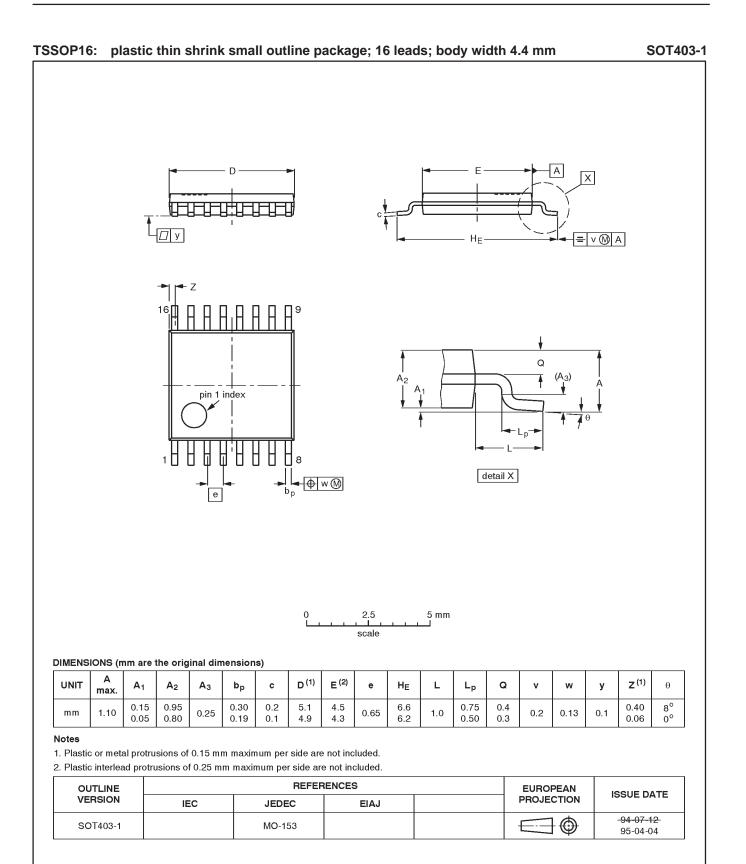


REFERENCES OUTLINE EUROPEAN ISSUE DATE VERSION PROJECTION IEC JEDEC EIAJ 91-08-13 \odot SOT109-1 076E07S MS-012AC Ð 95-01-23

Product specification



Product specification



Product specification

8-channel analog multiplexer/demultiplexer

74LV4051

NOTES

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DEFINITIONS		
Data Sheet Identification	Product Status	Definition
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